General Product Information

Absolute Maximum Ratings





EYP-DFB-0780-00040-1500-BFW11-0005

Revision

2022-01-19

SINGLE FREQUENCY LASER DIODES Distributed Feedback Laser



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Product	Application
780 nm DFB Laser	· · · · · · · · · · · · · · · · · · ·
	Spectroscopy (Rb D2 line)
with hermetic 14-Pin Butterfly Housing (RoHS compliant)	Metrology
including Monitor Diode, Thermoelectric Cooler and Thermistor	THz Generation
with integrated μ Isolator and Beam Collimation	



U					
Parameter	Symbol	Unit	min	typ	max
Storage Temperature	T _s	°C	-40		85
Operational Temperature at Case	T_{C}	°C	-40		85
Operational Temperature at Laser Chip	T_{LD}	°C	5		50
Forward Current	I _F	mA			190
Reverse Voltage	V_R	V			2
Output Power	P _{opt}	mW			50
TEC Current	I _{TEC}	А			1.1
TEC Voltage	V_{TEC}	V			2.8

Parameter	Symbol	Unit	min	typ	max
Operational Temperature at Case	T_{case}	°C	-20		65
Operational Temperature at Laser Chip	T_{LD}	°C	5		45
Forward Current	I _F	mA			180
Output Power	P _{opt}	mW	10		40

Measurement Conditions / Comments	
measured by integrated Thermistor	
, i	

Characteristics at T _{LD}	= 25° C at BOL				
Parameter	Symbol	Unit	min	typ	max
Center Wavelength	λ_{\subset}	nm	779	780	781
Target Wavelength	λ_{T}	nm		780.24	
Linewidth (FWHM)	Δλ	MHz		0.6	1
Mode-hop free Tuning Range	$\Delta \lambda_{\text{tune}}$	pm	25		
Sidemode Supression Ratio	SMSR	dB	30	50	

Measurement Conditions / Comments
see images on page 4
reached within $T_{LD} = 5$ ° 45 ° C at 40 mW
$P_{opt} = 80 \text{ mW}$
> 10 GHz, at target wavelength
$P_{opt} = 40 \text{ mW}$

EYP-DFB-0780-00040-1500-BFW11-0005



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Characteristics at T _{LD} = 25° C	at BOL				cont'd
Parameter	Symbol	Unit	min	typ	max
Temperature Coefficient of Wavelength	dλ / dT	nm / K		0.06	
Current Coefficient of Wavelength	dλ / dl	nm / mA		0.003	
Laser Current @ P _{opt} = 40 mW	I_{LD}	mA			180
Slope Efficiency	η	W/A	0,3	0,4	0.6
Threshold Current	I _{th}	mA			70
Divergence parallel (FWHM)	$\Theta_{ }$	0		0.1	
Divergence perpendicular (FWHM)	Θ_{\perp}	0		0.1	
Beam Diameter horizontal	d	mm		1.0	1.2
Beam Diameter vertical	d_\perp	mm		0.8	1.2
Degree of Polarization	DOP	%		95	

Measurement Conditions / Comments
parallel to the base plate of the housing (see p. 3)
perpendicular to base plate of the housing (see p. 3)
parallel to the base plate of the housing (see p. 3)
perpendicular to base plate of the housing (see p. 3)
$P_{opt} = 40$ mW; slant polarization (45°), see p. 3

Symbol	Unit	min	typ	max
I _{mon} / P _{opt}	μA/mW	2		40
		Symbol Unit		.,

Measurement Conditions / Comments	
$U_R = 5 V$	

Thermoelectric Cooler					
Parameter	Symbol	Unit	min	typ	max
Current	I _{TEC}	А		0.4	
Voltage	U_TEC	V		1.3	
Power Dissipation (total loss at case)	P _{loss}	W		0.5	
Temperature Difference	ΔΤ	K			50

Measurement Conditions / Comments					
$P_{opt} = 40 \text{ mW}, \Delta T = 20 \text{ K}$					
$P_{opt} = 40$ mW, $\Delta T = 20$ K					
$P_{opt} = 40$ mW, $\Delta T = 20$ K					
$P_{opt} = 40 \text{ mW}, \Delta T = Tcase - TLD $					

Thermistor (Standard NTC Type)					
Parameter	Symbol	Unit	min	typ	max
Resistance	R	kΩ		10	
Beta Coefficient	β			3892	
Steinhart & Hart Coefficient A	Α			1.1293 x 10) -3
Steinhart & Hart Coefficient B	В			2.3410 x 10) -4
Steinhart & Hart Coefficient C	С			8.7755 x 10) ⁻⁸

Measurement Conditions / Comments					
$T_{LD} = 25^{\circ} C$					
$R_1 / R_2 = e^{ \beta (1/T_1 - 1/T_2)} $ at $T_{LD} =$	0° 50° C				
$1/T = A + B(\ln R) + C(\ln R)^3$					
T: temperature in Kelvin					
R: resistance at T in Ohm					

EYP-DFB-0780-00040-1500-BFW11-0005



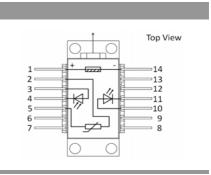
Revision

2022-01-19

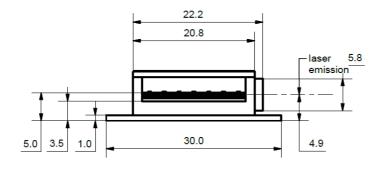
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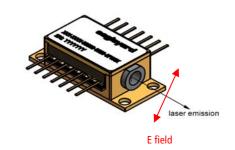


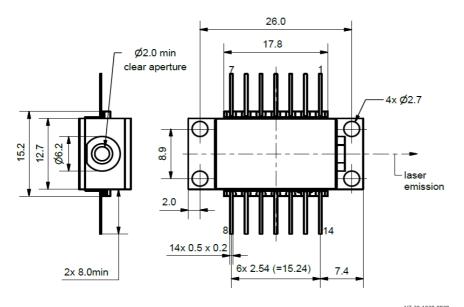
Pin	Pin Assignment							
1	Thermoelectric Cooler (+)	14	Thermoelectric Cooler (-)					
2	Thermistor	13	Case					
3	Photodiode (Anode)	12	not connected					
4	Photodiode (Cathode)	11	Laser Diode (Cathode)					
5	Thermistor	10	Laser Diode (Anode)					
6	not connected	9	not connected					
7	not connected	8	not connected					



Package Drawings







Caution. Excessive mechanical stress on the package can lead to a damage of the laser.

instruction manual on www.eagleyard.com

EYP-DFB-0780-00040-1500-BFW11-0005



Revision

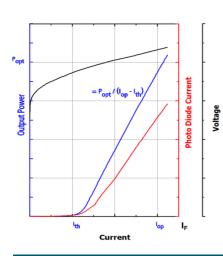
2022-01-19

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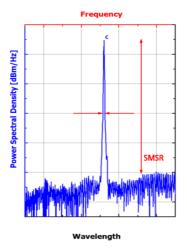


Typical Measurement Results

Output Power vs. Current



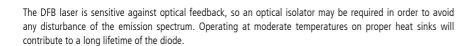
Spectra at Specified Optical Output Power



Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.

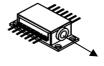
Unpacking, Installation and Laser Safety

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.



Avoid direct and/or indirect exposure to the free running beam. Collimating and focussing the free running beam with optics as common in optical instruments will increase threat to the human eye.

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Laser Emission







